

Look back ...

- We know what the carriers in semiconductors are. (Electrons, holes)
- We know how they move inside the semiconductor (effective mass)
- But we still do not know how many carriers are there.

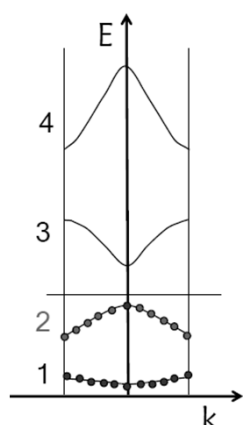


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39

Density of States



- A single band has totally N states
- Only a fraction of the states are occupied.
- How many states are occupied up to E ?
- Or equivalently, how many states are occupied per unit energy?

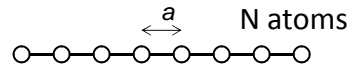


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40

Density of States in 1D Semiconductors

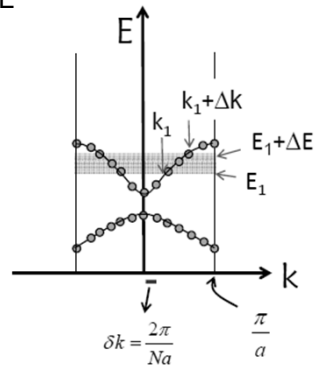


of States between state E_1 & $E_1 + \Delta E$

$$= \frac{\Delta k}{\delta k} \times 2 = \frac{\Delta k}{2\pi/Na} \times 2$$

of states/unit energy at E_1

$$= \frac{Na \Delta k}{\pi \Delta E}$$

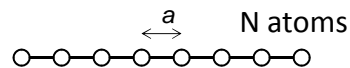


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41

1D DOS



$$\text{States/unit energy @ } E = \frac{Na \Delta k}{\pi \Delta E}$$

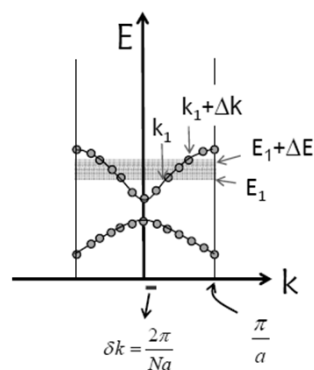
$$E - E_0 = \frac{\hbar^2 k^2}{2m^*} \Rightarrow k = \sqrt{\frac{2m^*(E - E_0)}{\hbar^2}}$$

$$\frac{dk}{dE} = \sqrt{\frac{m^*}{2\hbar^2(E - E_0)}}$$

$$\text{States/unit energy @ } E = \frac{L}{\pi} \sqrt{\frac{m^*}{2\hbar^2(E - E_0)}}$$

States/unit energy/unit length @ E

$$\equiv \text{DOS} = \frac{1}{\pi} \sqrt{\frac{m^*}{2\hbar^2(E - E_0)}}$$

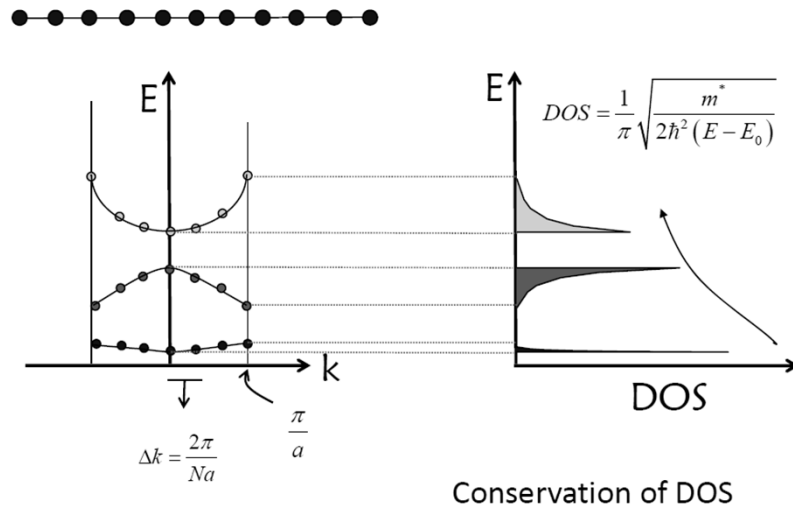


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42

1D-DOS cont'd



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43

3D Density of States

States between $E_1 + \Delta E$ & E_1

$$= \frac{\frac{4}{3}\pi(k+dk)^3 - \frac{4}{3}\pi k^3}{\frac{2\pi}{L} \frac{2\pi}{W} \frac{2\pi}{H}} = \frac{V}{2\pi^2} k^2 \Delta k$$

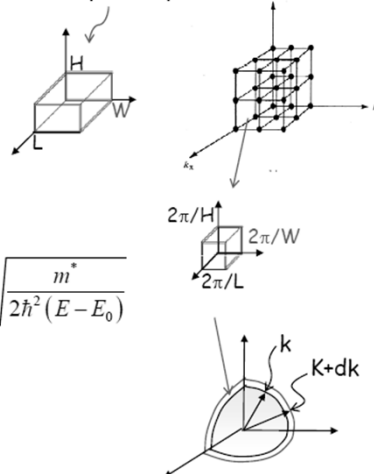
$$\text{States/unit energy @ } E = \frac{V}{2\pi^2} k^2 \frac{\Delta k}{dE}$$

$$E - E_0 = \frac{\hbar^2 k^2}{2m^*} \Rightarrow k = \sqrt{\frac{2m^*(E-E_0)}{\hbar^2}} \Rightarrow \frac{dk}{dE} = \sqrt{\frac{m^*}{2\hbar^2(E-E_0)}}$$

States/unit energy/unit volume @ E_1

$$DOS = \frac{m^*}{2\pi^2 \hbar^3} \sqrt{2m^*(E-E_0)}$$

Macroscopic Sample

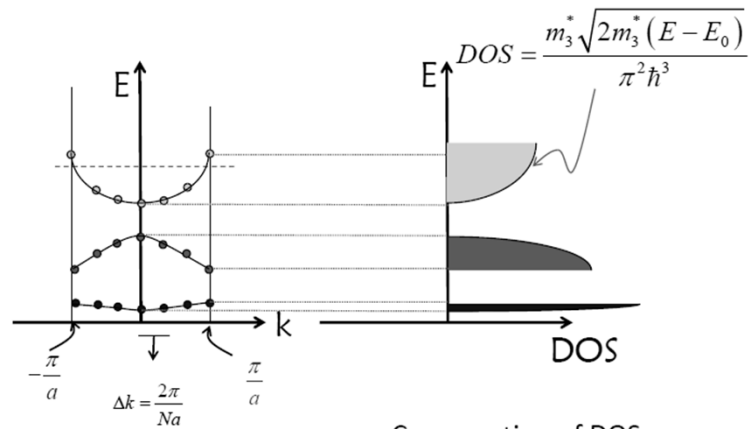


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44

3D-DOS



Conservation of DOS

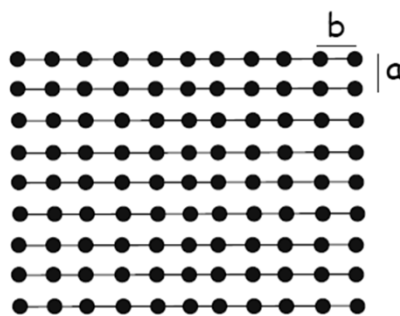


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45

2D DOS?



This is a homework problem.

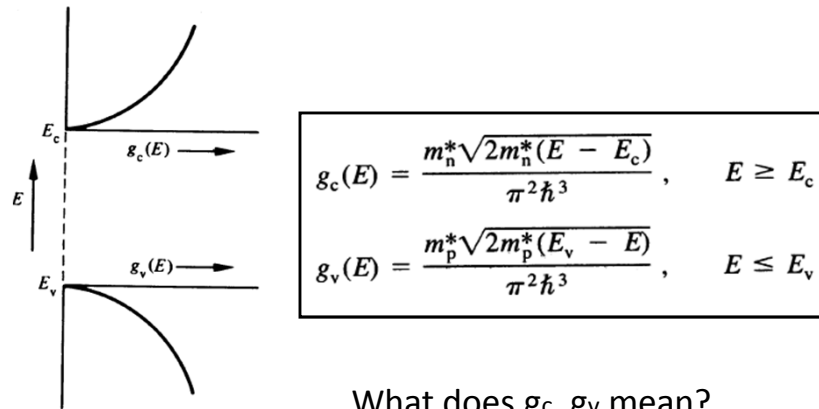


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46

Density of States for Electrons and Holes



What does g_c , g_v mean?



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47